



Preparation of 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf heterojunctions with well-designed high-speed charge transfer nanochannels towards high-efficiency photocatalytic hydrogen evolution

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ABSTRACT

In this work, we design and construct a novel 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf via a simple one-step surfactant-assisted solvothermal method for photocatalytic H₂ generation. Its unusual 2D/2D heterojunction structure provides far more contact areas and much faster charge transport rate than the 2D/0D heterojunction structure of g-C₃N₄ nanosheet@ZnIn₂S₄ microsphere. More importantly, this unique 2D/2D heterojunction leads the g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf composite to generate numerous intimate high-speed charge transfer nanochannels in the interfacial junctions, and which could considerably enhance the photogenerated charge separation and migration efficiency, thus yielding a remarkable visible-light-driven H₂ evolution rate without the additive Pt cocatalyst (HER = 2.78 mmol h⁻¹ g⁻¹), nearly 69.5, 15.4, 8.2 and 1.9 times higher than that of pure g-C₃N₄ nanosheet, pure ZnIn₂S₄ microsphere, 2D/0D g-C₃N₄ nanosheet@ZnIn₂S₄ microsphere and pure ZnIn₂S₄ nanoleaf, respectively. Additionally, the 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf exhibits an outstanding stability and recyclability, manifesting a promising potential application in sustainable energy conversion. This work would provide a platform for the design and synthesis of binary heterojunction composite system with highly-efficient charge separation and transfer.

1. Introduction

The high-efficiency utilization of solar energy is a desirable and scalable strategy to handle the crises of ever growing global energy demand and severe environmental concerns. The semiconductor photocatalysis technology is precisely the key to advance the sunlight exploitation into feasible industrial applications, such as energy conversion [1,2], environmental protection [3,4], and organic synthesis [5,6]. Nevertheless, the considerably high recombination rate of photoexcited electron-hole pairs for single-component photocatalysts is the major obstacle to achieve a high quantum efficiency and photocatalytic activity, thus limiting the practical application of photocatalysis technology, just like single pristine bulk graphitic carbon nitride (g-C₃N₄), which although has gained considerable attention due to its attractive electronic and optical properties, facilely tunable electronic structure, remarkable chemical and thermal stability, low economic cost and environmental friendliness [7–9], the g-C₃N₄ still shows quite low photocatalytic activity with quantum efficiency of approximately 0.1%

under visible-light irradiation owing to its highly photogenerated charge recombination rate [10,11]. Therefore, significant efforts have been made to design and construct the multicomponent heterostructured photocatalysts which could effectively accelerate the separation and migration of photogenerated charges, and this design strategy has been shown huge advantages for the enhancement of visible-light photocatalytic activity of g-C₃N₄-based heterostructured composite.

Recently, as a new and important member in the community of ternary chalcogenide (simplified as AB₂X₄, A = Zn, Ca, Cu, Cd; B = Al, Ga, In; X = S, Se, Te), ZnIn₂S₄ with a typical layered structure has triggered keen interest in photocatalysis due to its excellent electrical and optical properties, strong visible-light harvesting ability and remarkable chemical stability [12–14]. More importantly, as previously reported [10,12,15], ZnIn₂S₄ has a matched band gap structure with g-C₃N₄, which makes it possible to construct the binary heterojunction system of g-C₃N₄@ZnIn₂S₄ to improve the charge separation and migration efficiency for g-C₃N₄. In the recent work, Liu and Jin *et al.* [12]

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have reported the synthesis of $\text{ZnIn}_2\text{S}_4@\text{g-C}_3\text{N}_4$ nanocomposites using the hydrothermal method, which exhibits high photocatalytic hydrogen evolution. Liu and Chen et al. [15] have also fabricated $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoparticles with an improved photocatalytic activity using a hydrothermal strategy. However, these above conventionally prepared $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$ binary composites present a typical 2D/0D type (face-to-point) heterojunction, and the 2D/0D heterojunction owns the micron-sized bulk aggregate structure and very small contacted interface between $\text{g-C}_3\text{N}_4$ nanosheet and ZnIn_2S_4 agglomerate, thus a severe traffic congestion of charges can be easily happened in the contacted interface. Besides, the photogenerated charges on the inside of the ZnIn_2S_4 agglomerates have to transfer along the longer route to the ZnIn_2S_4 surfaces in the photocatalytic reaction. These above charge transfer processes would lead to the poor charge separation and migration efficiency as well as low photocatalytic activity for 2D/0D $\text{ZnIn}_2\text{S}_4@\text{g-C}_3\text{N}_4$ composite. Hence, the design of effective heterojunction with intimate interface contact between $\text{g-C}_3\text{N}_4$ and ZnIn_2S_4 is considered to be a promising protocol to significantly accelerate the charge separation and migration in the binary heterojunction system of $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$.

According to the aforementioned motivation, the 2D/2D heterojunction is precisely the desired heterojunction that we earnestly seek. From the viewpoint of binary two-dimensional $\text{g-C}_3\text{N}_4$ -based heterojunction microstructures, the 2D/2D type $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$ heterojunction owns many unique advantages by contrast with 2D/0D type one [16,17]: Firstly, the 2D/2D face-to-face heterojunction formed between $\text{g-C}_3\text{N}_4$ nanosheet and ZnIn_2S_4 nanosheet has much more contact areas than the 2D/0D face-to-point $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$ composite. Secondly, the 2D/2D type $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$ heterojunction shortens the migration distance and time of photoinduced charges. Therefore, the construction of 2D/2D type heterojunction can produce a lot of unique high-speed charge transfer nanochannels in $\text{g-C}_3\text{N}_4@\text{ZnIn}_2\text{S}_4$ composite, which mean that the photoinduced charges transfer along the expected migration route (from $\text{g-C}_3\text{N}_4$ nanosheet to the intimate heterojunction interface then to ZnIn_2S_4 nanosheet), similarly to the freeways in real life, thus contributing to the fairly high charge separation and transfer efficiency as well as outstanding photocatalytic activity. However, thus far, no report has been available on the construction of 2D/2D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanosheet photocatalyst.

Herein, we first design and construct a novel 2D/2D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf (a nano-sized ZnIn_2S_4 sheet similarly to the leaf in nature) with the unique high-speed charge transfer nanochannels achieved by in-situ growing unique ZnIn_2S_4 nanoleaves on the surfaces of $\text{g-C}_3\text{N}_4$ nanosheets via a simple one-step surfactant-assisted solvothermal method. The resultant 2D/2D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf exhibits a remarkable hydrogen evolution activity without the additive Pt cocatalyst, far exceeding the 2D/0D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 microsphere. Various characterization methods, such as XRD, SEM, TEM, PL and transient fluorescence decay spectra, are explored to shed light on the intrinsic link between the 2D/2D geometry structure and significantly enhanced photocatalytic activity for the resultant $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf heterojunction.

2. Experimental

2.1. Material synthesis

All reagents for synthesis and analysis were analytical grade and used without further purification.

2.1.1. Synthesis of bulk $\text{g-C}_3\text{N}_4$

10 g of melamine was directly calcined at 550 °C for 4 h in air with a heating rate of 2.3 °C·min⁻¹, the resultant canary powder was collected as a reference and denoted as BCN.

2.1.2. Synthesis of $\text{g-C}_3\text{N}_4$ nanosheet

3 g of above bulk $\text{g-C}_3\text{N}_4$ was exposed to air and calcined at 520 °C for 5 h, the resultant white powder was collected for the further use and denoted as CNNs.

2.1.3. Synthesis of pure ZnIn_2S_4 nanoleaf

0.030 g of $\text{Zn}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ (0.1 mmol), 0.076 g of $\text{In}(\text{NO}_3)_3 \cdot 4.5\text{H}_2\text{O}$ (0.2 mmol) and a certain amount of trisodium citrate dihydrate were dissolved in 30 mL of deionized water, and vigorously stirred at room temperature for 0.5 h. Then 0.060 g of thioacetamide (TAA, 0.8 mmol) was ultrasonically dissolved in the above solution and vigorously stirred at same temperature for 0.5 h. Next, the above mixture solution was transferred to a 100 mL Teflon-lined stainless steel autoclave and heated at 160 °C for 1 h. After cooling down to room temperature, the sample was collected by the centrifugation, washed several times using deionized water and ethanol, and dried in a drying oven at 60 °C for 24 h. The resultant product was denoted as PZN. As a reference, the pure ZnIn_2S_4 microsphere was synthesized under the similar conditions, and the only difference is the lack of trisodium citrate dihydrate. The resultant pure ZnIn_2S_4 microsphere was denoted as PZM.

2.1.4. Synthesis of 2D/2D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf

The 2D/2D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf was synthesized by a simple surfactant-assisted solvothermal method. In detail, 0.030 g of $\text{Zn}(\text{NO}_3)_2 \cdot 6\text{H}_2\text{O}$ (0.1 mmol), 0.076 g of $\text{In}(\text{NO}_3)_3 \cdot 4.5\text{H}_2\text{O}$ (0.2 mmol) and a certain amount of trisodium citrate dihydrate were dissolved in 30 mL of deionized water, and vigorously stirred at room temperature for 0.5 h. Then 0.020 g of $\text{g-C}_3\text{N}_4$ nanosheet was ultrasonically dispersed in the above solution and vigorously stirred at same temperature for 3 h. Next, 0.060 g of thioacetamide (TAA, 0.8 mmol) was ultrasonically dissolved in the above solution and vigorously stirred at same temperature for 0.5 h. Finally, the above mixture solution was transferred to a 100 mL teflon-lined stainless steel autoclave and heated to 160 °C and kept for 1 h. After cooling down to room temperature, the sample was collected by the centrifugation, washed several times using deionized water and ethanol, and dried in drying oven at 60 °C for 24 h. The resultant product was denoted as GN@ZN. Furthermore, the 2D/0D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 microsphere was synthesized as a reference. The preparation process of 2D/0D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 microsphere is similar to that of GN@ZN, and the only difference is the lack of trisodium citrate dihydrate. The resultant 2D/0D $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 microsphere was denoted as GN@ZM. Additionally, a mechanically mixed $\text{g-C}_3\text{N}_4$ nanosheet@ ZnIn_2S_4 nanoleaf (MMGZ) sample was also obtained by finely grinding 0.2 g of $\text{g-C}_3\text{N}_4$ nanosheet and 0.4 g of pure ZnIn_2S_4 nanoleaf.

2.2. Characterization

The as-prepared products were characterized by a variety of techniques. The crystal structure of products was analyzed with the help of a powder X-ray diffraction (Lab X XRD-6100, SHIMADZU). The morphologies of the resultant samples were observed by a field emission scanning electron microscope (JSM-6700F, JEOL) and a transmission electron microscopy (JEM-2100, JEOL). The elementary composition of samples was analyzed by the energy dispersive X-ray spectroscopy (EDX) and elemental mapping. The Brunauer-Emmett-Teller (BET) specific surface areas were recorded on an automatic BET analyzer (Autosorb-iQ-TPX, Quantachrome), and the products were degassed at 160 °C for 6 h before the N_2 adsorption measurements. Steady photoluminescence (PL) emission spectra and transient fluorescence decay spectra were tested by a luminescence spectrophotometer (QM-400, PTI) with 340 nm excitation wavelength. Ultraviolet-visible (UV-vis) diffuse reflectance spectra (DRS) were obtained using a UV-vis spectrophotometer (UV-2600, SHIMADZU). Additionally, the valence band (E_{VB}) and conduction band (E_{CB}) edge

potentials of samples can be determined by the following two formulas:

$$E_{VB} = X \cdot E_e + 0.5 \times E_g \quad (1)$$

$$E_{CB} = E_{VB} - E_g \quad (2)$$

Where E_e represents the free electron energy on the hydrogen scale (4.5 eV), and X represents the absolute electronegativity of semiconductor materials. The X values for g-C₃N₄ and ZnIn₂S₄ are 4.73 eV and 4.86 eV, respectively [4,12].

2.3. Photocatalytic activity measurement

The photocatalytic hydrogen production was conducted in an outer Pyrex reactor (100 mL). 0.05 g of powder photocatalyst was suspended into an aqueous solution (50 mL) containing 10 mL of triethanolamine (sacrificial electron donor). Prior to the reaction, the reaction solution was deaerated by the bubbled treatment with high purity nitrogen to remove air completely. Then the reaction was carried out under the illumination of a 300 W Xenon lamp (HSX-F300, NbeT, Beijing) equipped with a 420 nm cutoff filter. The evolved gases were detected by a gas chromatograph (SP-2100A, Beifen-Ruili) equipped with a 5 Å molecular sieve and a TCD detector.

The apparent quantum yield (AQY) for the obtained samples was tested under the same reaction conditions, the only difference is that a 420 nm band-pass filter is used to obtain the monochromatic light ($\lambda = 420$ nm), and the average irradiation intensity received by the reactor is 52.8 mW cm⁻². The AQY was evaluated by the following equation:

$$\text{AQY}(\%) = \frac{2 \times \text{number of evolved hydrogen molecules}}{\text{number of incident photons}} \quad (3)$$

2.4. Photoelectrochemical measurement

The photocurrent response and electrochemical impedance spectroscopy of the samples were tested by a CHI 660D type electrochemical station (Chenhua, China) and a PMC-1000/DC type one (AMETEK), respectively. The two kinds of measurements are in the same three-electrode system. In this system, the Na₂SO₄ aqueous solution (1 M) was used as the electrolyte. The Ag/AgCl electrode and platinum wire were chosen as the reference electrode and the counter electrode, respectively. The glassy carbon electrodes containing the as-prepared products were served as the working electrodes.

3. Results and discussion

The overall formation procedure of 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf is presented in Fig. 1. Firstly, the initial bulk g-C₃N₄ (BCN) was fabricated by the thermal-induced self-condensation of melamine heating at 550 °C for 4 h in air. Thereafter, the BCN was exfoliated and transformed into g-C₃N₄ nanosheet (CNNs) via a thermal oxidation process calcining at 520 °C for 5 h in air. When the CNNs was dispersed and stirred in the aqueous solution containing Zn (NO₃)₂ · 6H₂O, In(NO₃)₃ · 4.5H₂O and trisodium citrate dihydrate, the cations of Zn²⁺ and In³⁺ readily loaded on the surfaces of negatively charged CNNs through electrostatic attraction effect [10]. After that,

along with the addition of thioacetamide, the generated S²⁻ reacted with absorbed Zn²⁺ and In³⁺ to obtain numerous ZnIn₂S₄ nanoparticles on the CNNs flat. It is noted that the generated ZnIn₂S₄ nanoparticles would be covered by the trisodium citrate dihydrate molecules, which effectively restrain the growth of ZnIn₂S₄ and make it slowly change into nanoleafy structure with an average length of 55 nm and an average width of 10 nm under the solvothermal condition. Ultimately, a large number of ZnIn₂S₄ nanoleaves uniformly distribute on the CNNs flat in the unique face-to-face way to obtain 2D/2D g-C₃N₄@ZnIn₂S₄ binary heterojunction system.

Fig. 2 exhibits the typical X-ray diffraction (XRD) patterns of the obtained products. As shown in Fig. 2a, two evident characteristic peaks could be clearly observed in the curves of BCN and CNNs. The minor diffraction peak at 12.9° corresponds to the (100) crystal plane of g-C₃N₄ derived from the repetitive in-plane structural packing motif of tri-s-triazine units [18]. In regard to the initial BCN sample, the prominent and sharp diffraction peak at 27.4° can be assigned to the interlayer-stacking (002) reflection of melon networks [19]. It is noteworthy that the (002) reflection peak in the curve of CNNs displays the relatively weak intensity and a tiny shift from 27.4° to 27.7°, this shift is due to the reduced interplane distance after thermal oxidation exfoliation treatment [19]. With respect to the samples of pure ZnIn₂S₄ microsphere and pure ZnIn₂S₄ nanoleaf, as displayed in Fig. 2b, all XRD diffraction peaks belong to the hexagonal crystal structure of ZnIn₂S₄ ($a=b=3.85$ Å, $c=24.68$ Å), which well conforms to the JCPDS data (ICDD-JCPDS card no. 72-0773) [13,20,21]. For the products of 2D/OD GN@ZM and 2D/2D GN@ZN, a strong diffraction peak at around 27.9° appeared in both of the curves can be attributed to the overlap of the (002) reflection peak of g-C₃N₄ nanosheet (27.7°) and the (102) reflection peak of hexagonal ZnIn₂S₄ (28.2°). Additionally, all other diffraction peaks in the two composite samples are corresponded to the crystal planes of hexagonal ZnIn₂S₄, indicating the successful formation of g-C₃N₄@ZnIn₂S₄ binary heterojunction composite.

The morphologies of the resultant products are measured by the scanning electron microscopy (SEM, Fig. 3) and transmission electron microscopy (TEM, Fig. 4). Figs. 3a and 4a show the typical micron-sized bulk morphology for BCN. It can be seen that the bulk g-C₃N₄ has been exfoliated into a thinner g-C₃N₄ nanosheet after thermal oxidation exfoliation (Figs. 3b and 4b), and the formation of g-C₃N₄ nanosheet can effectively shorten the vertical movement distance of photoinduced charges and thus restrain the charge recombination in the inside of g-C₃N₄. In regard to PZM, it can be clearly found that several ZnIn₂S₄ microspheres aggregate to form irregular agglomerates (Figs. 3c and 4c). However, with the help of trisodium citrate dihydrate, numerous uniformly dispersed ZnIn₂S₄ nanosheets similarly to the leaves in nature are shown in SEM and TEM images of PZN (Figs. 3d and 4d), and the individual ZnIn₂S₄ nanoleaf has an average length of 55 nm and an average width of 10 nm (see the inset of Fig. 4d). The novel nano-sized leafy morphology is beneficial for the charge separation, significantly promoting the enhancement of photocatalytic activity. In Figs. 3e and 4e, many irregular ZnIn₂S₄ agglomerates, like microsphere structure, randomly disperse on the flat of CNNs in the face-to-point way to obtain 2D/OD g-C₃N₄@ZnIn₂S₄ binary heterojunction composite, this 2D/OD type heterojunction has an extremely limited contact area, and tends to cause a serious traffic congestion when the photogenerated charges transfer through the contact area, resulting in a slow charge transport

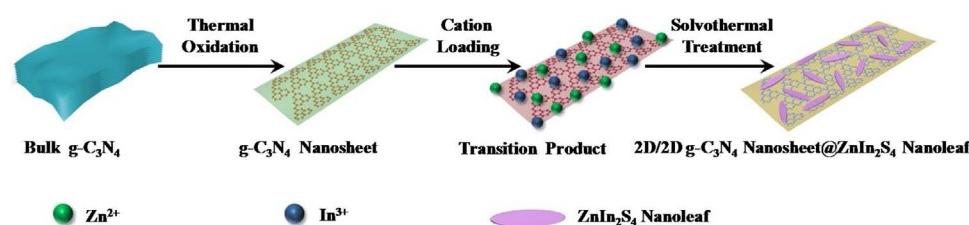


Fig. 1. Schematic sketch of formation procedure of 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf.

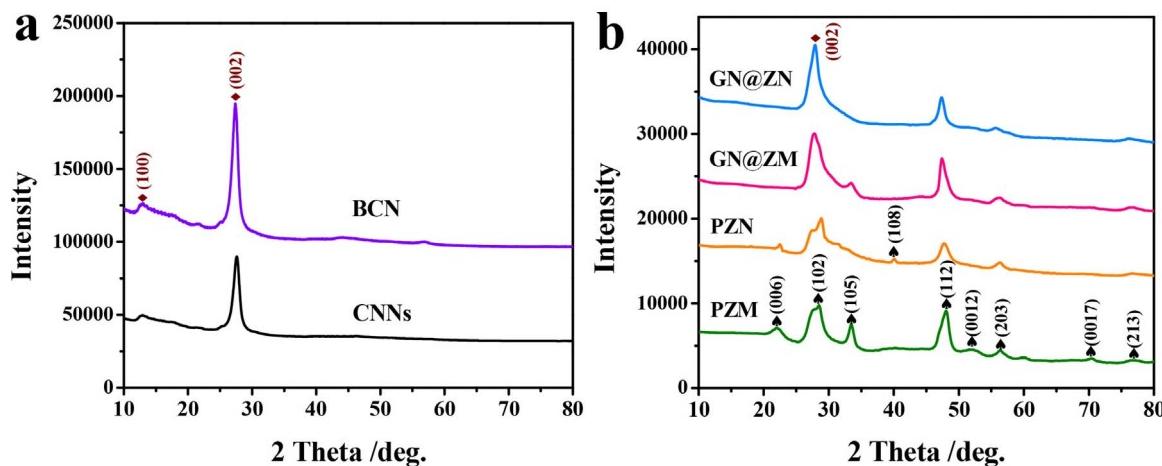


Fig. 2. (a) X-ray diffraction patterns of BCN and CNNs. (b) X-ray diffraction patterns of PZM, PZN, GN@ZM and GN@ZN.

rate. Differing from 2D/0D GN@ZM, the sample of 2D/2D GN@ZN shows an optimal g-C₃N₄@ZnIn₂S₄ heterojunction structure (Figs. 3f and 4f): Massive well-dispersed nanoscale ZnIn₂S₄ nanoleaves uniformly grow on the surfaces of g-C₃N₄ nanosheet flat. The magnification TEM (Fig. 4g, h) further manifests the ZnIn₂S₄ nanoleaves sufficiently contact with g-C₃N₄ nanosheet in the face-to-face way and thus form vast effective heterojunction interfaces. This unique spatial arrangement of g-C₃N₄ and ZnIn₂S₄ in 2D/2D GN@ZN could create abundant high-speed charge transfer nanochannels, greatly improving charge separation and migration efficiency. The HR-TEM image of 2D/2D GN@ZN (Fig. 4i) clearly confirms the presence of intimate 2D/2D heterojunction interface, where the lattice-fringe spacing of 0.321 nm is indexed to the (102) reflection plane of hexagonal ZnIn₂S₄, and this (102) reflection plane is attached closely to the amorphous area of g-C₃N₄ to form the 2D/2D heterojunction. Additionally, to further investigate the compositions and element distributions of 2D/2D GN@ZN, the energy-dispersive X-ray (EDX) elemental mapping tests are performed. As shown in Fig. 5a–f, the elemental mappings clearly reveal the uniform spatial distribution of rich elements, including carbon

(C), nitrogen (N), zinc (Zn), indium (In) and sulfur (S), indicating that ZnIn₂S₄ nanoleaves uniformly distribute on the surfaces of g-C₃N₄ nanosheet flat, strongly supporting the SEM and TEM observations. The above-mentioned elements in 2D/2D GN@ZN are also confirmed by EDX measurement (Fig. 5g, h).

Time-dependent photoinduced H₂ evolution for different photocatalysts has been carried out in an aqueous solution containing triethanolamine (sacrificial electron donor) without the additive Pt cocatalyst under visible-light irradiation ($\lambda \geq 420$ nm). As illustrated in Fig. 6a, the pristine g-C₃N₄ displays negligible hydrogen-evolution rate (HER), and after the thermal exfoliation treatment, the g-C₃N₄ nanosheet shows an enhanced HER value ($0.04 \text{ mmol h}^{-1} \text{ g}^{-1}$), manifesting the structure-induced merits of g-C₃N₄ nanosheet. Moreover, the PZM sample exhibits moderate HER of $0.18 \text{ mmol h}^{-1} \text{ g}^{-1}$. Interestingly, the PZN sample shows dramatically increased HER ($1.46 \text{ mmol h}^{-1} \text{ g}^{-1}$), nearly 8.1 times higher than that of PZM, strongly supporting the advantages of size control technology. When it comes to the g-C₃N₄@ZnIn₂S₄ binary heterojunction system, its structural advantages are directly reflected on the photocatalytic activity:

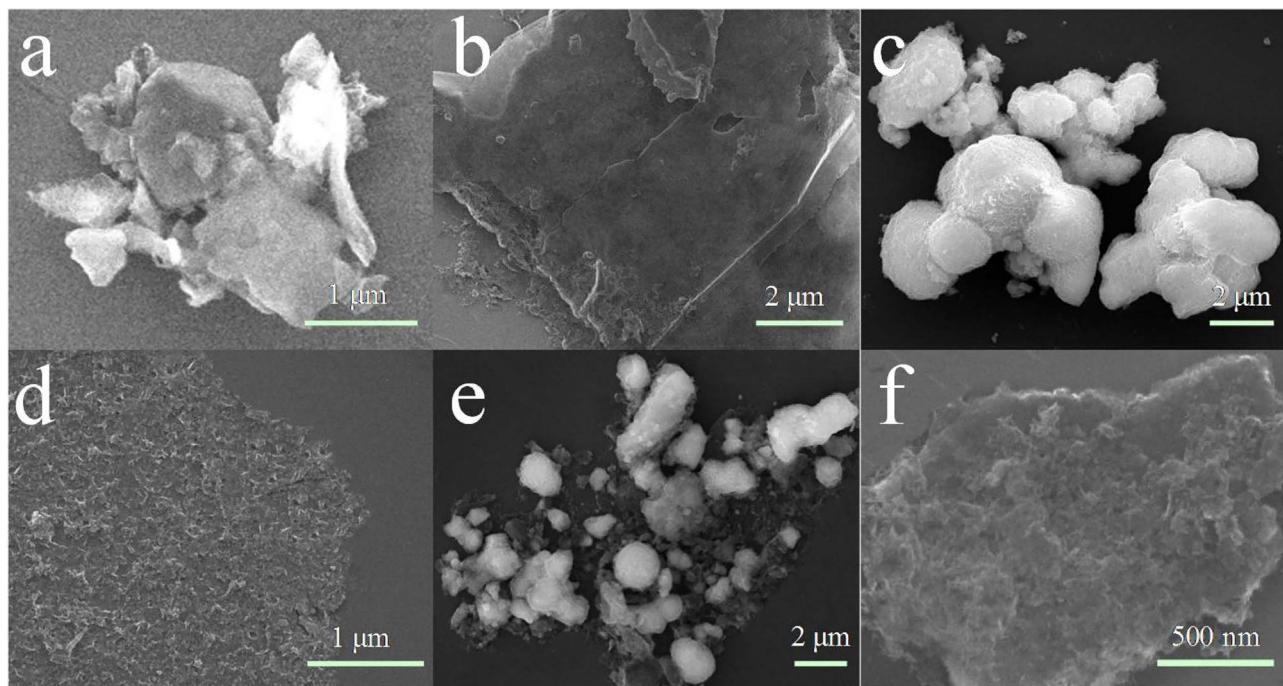


Fig. 3. SEM images of (a) BCN, (b) CNNs, (c) PZN, (d) PZM, (e) GN@ZM and (f) GN@ZN.

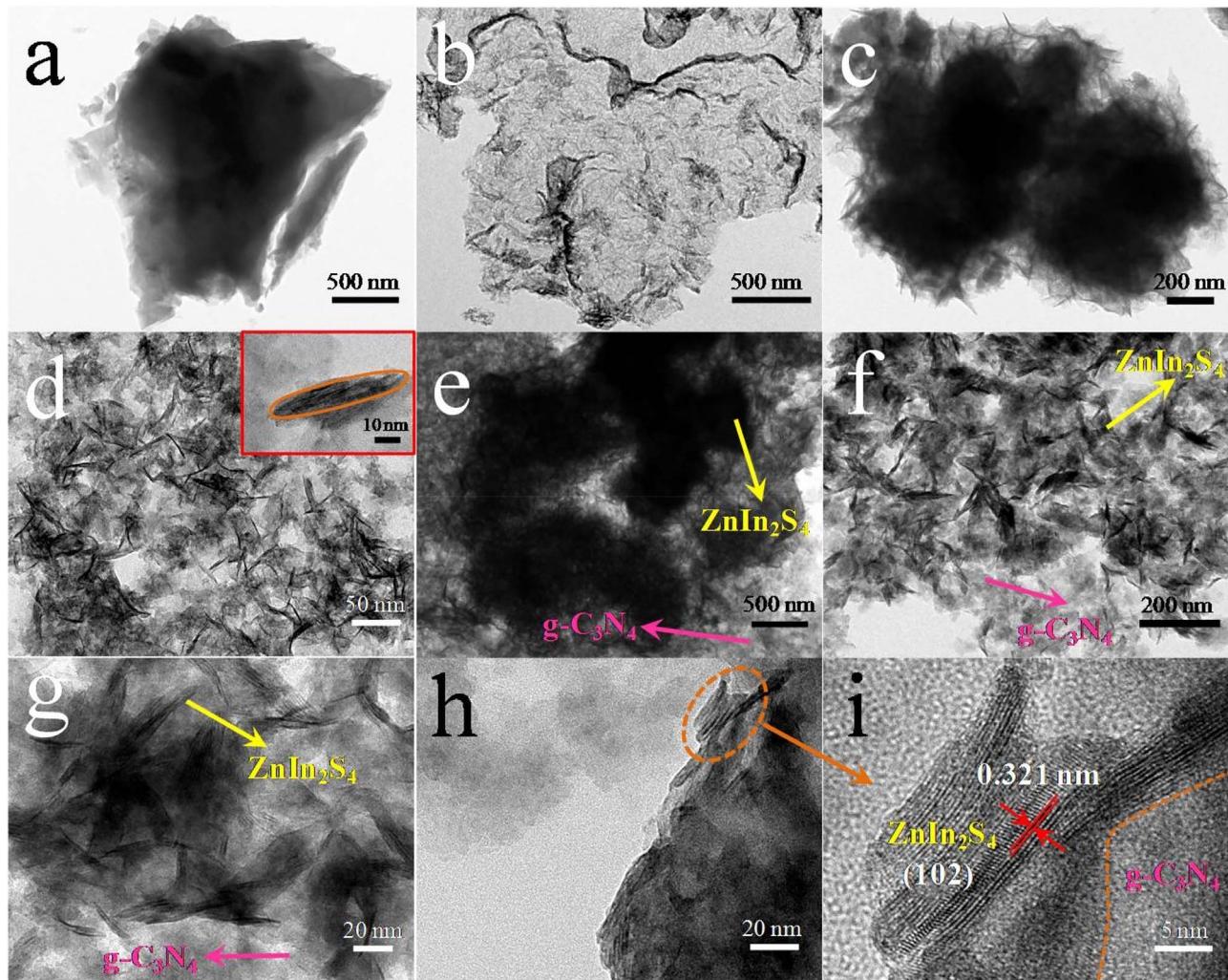


Fig. 4. TEM images of (a) BCN, (b) CNNs, (c) PZM, (d) PZN and (e) GN@ZM and (f) GN@ZN. Inset in (d): The magnification TEM image of individual ZnIn₂S₄ nanoleaf. The magnification TEM (g, h) of GN@ZN. HR-TEM image (i) of GN@ZN.

The 2D/0D GN@ZM has a HER of $0.34 \text{ mmol h}^{-1} \text{ g}^{-1}$, which is 1.89 times higher than that of PZM. Incredibly, the 2D/2D GN@ZN exhibits remarkable photocatalytic activity ($2.78 \text{ mmol h}^{-1} \text{ g}^{-1}$), and this value is nearly 69.5, 15.4, 8.2 and 1.9 times higher than that of CNNs, PZM, 2D/0D GN@ZM and PZN, respectively. More importantly, the HER of 2D/2D GN@ZN also far exceeds that of the majority of modified g-C₃N₄ in previous reports, even including numerous Pt-deposited photocatalysts (Fig. 6b) [7,12,22–32], indicative of the great advantages of the special 2D/2D heterojunction with high-speed charge transfer nanochannels. For comparison, a mechanically mixed g-C₃N₄ nanosheet and ZnIn₂S₄ nanoleaf sample was also synthesized, and the sample shows an extremely poor HER ($0.02 \text{ mmol h}^{-1} \text{ g}^{-1}$), again demonstrating the importance of the 2D/2D heterojunction for the photocatalytic H₂ evolution activity. To intuitively understand the significantly enhanced photocatalytic activity of 2D@2D heterojunction, the AQY of all the products has been measured under the monochromatic light irradiation ($\lambda = 420 \text{ nm}$). Both BCN and MMGZ samples show the negligible AQY value, while CNNs displays an extremely low AQY value of 0.01%. The PZN sample exhibits an AQY value of 3.80%, which is much higher than that of PZM sample (0.55%) due to its special leafy nanostructure. Furthermore, the 2D/2D GN@ZN owns the incredible AQY value of 7.05%, far outperforming the 2D/0D GN@ZM (1.01%). The results show that the construction of 2D/2D heterostructure is greatly beneficial for the enhancement of photocatalytic activity of g-C₃N₄ sample.

The stability and recyclability for the visible-light-driven photocatalytic hydrogen evolution over 2D/2D GN@ZN have been investigated under the same conditions. As shown in Fig. 6c, the resultant 2D/2D GN@ZN still maintains high photocatalytic hydrogen evolution activity after four photoreactions. Moreover, the TEM images in Fig. 7a show that the cyclic GN@ZN sample remains an intact morphology of the typical 2D/2D face-to-face structure after four photoreactions, similarly to the fresh 2D/2D GN@ZN sample (shown in Fig. 4f, g). Additionally, there is no obvious difference in the XRD patterns in both 2D/2D GN@ZN products before and after four photoreactions (Fig. 7b). These all prove that the novel 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf has an outstanding stability and recyclability, manifesting a promising potential application in sustainable energy conversion.

As shown in Fig. 6a, b, the construction of 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf heterostructure contributes to the remarkable activity for photocatalytic hydrogen evolution without the additive Pt cocatalyst, this would offer a new idea for the design and preparation of binary heterojunction composite system with the excellently catalytic performances. In order to better understand the effects of 2D/2D geometry structure on the above-mentioned outstanding photocatalytic activity for 2D/2D GN@ZN, it is necessary to discuss the origin of the significantly improved photocatalytic activity. As we know, the following factors, including optical absorption capacity, active surface area, photoinduced charge separation and migration efficiency, are three key scientific issues to influence the photocatalytic activity.

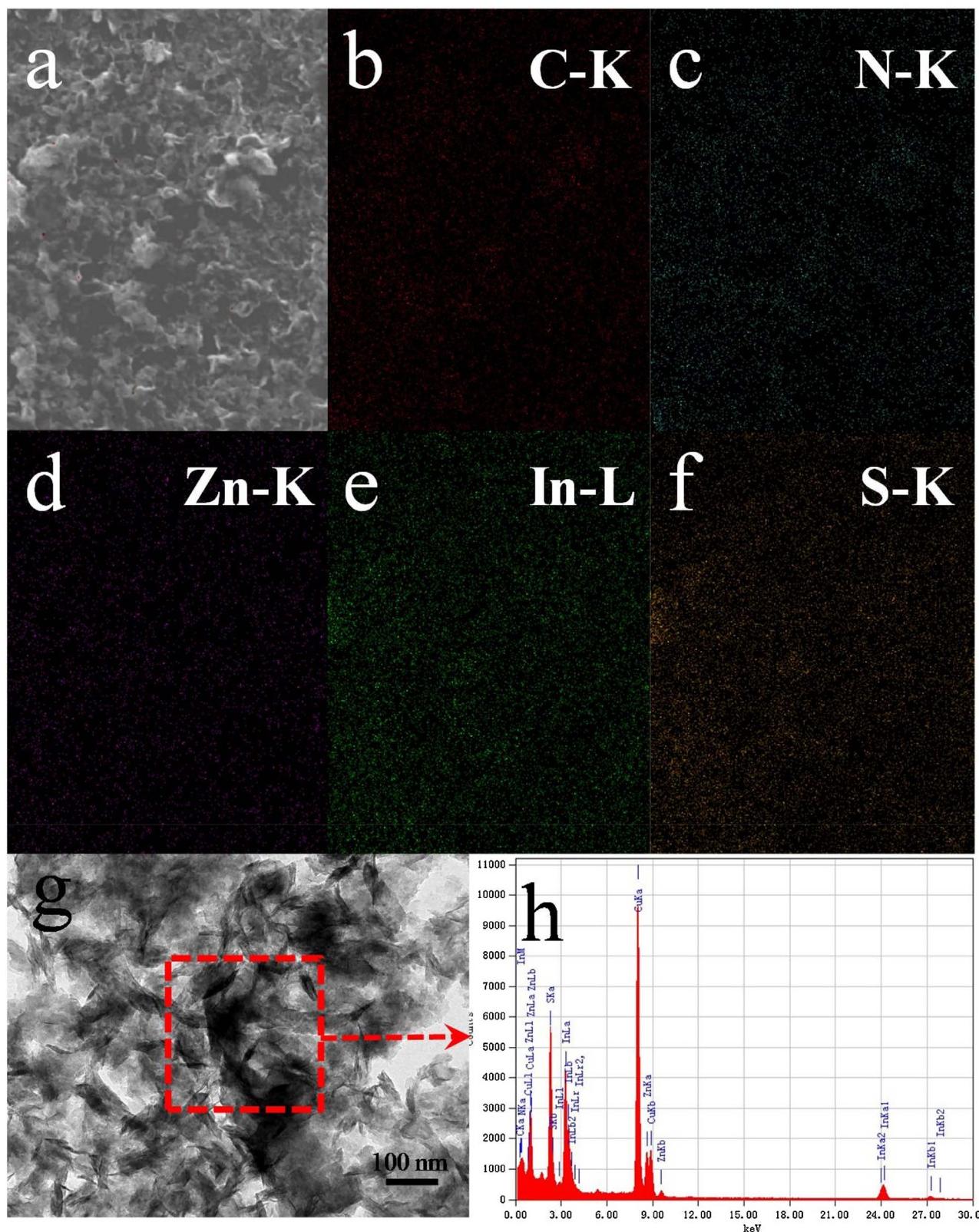


Fig. 5. Elemental mapping of (a) GN@ZN with the spatially resolved elements of (b) carbon, (c) nitrogen, (d) zinc, (e) indium and (f) sulfur. EDX images (g, h) of GN@ZN. The strong peaks for Cu are derived from the carbon-supported copper net applied to load the samples in TEM test.

Therefore, it is advisable and reasonable to investigate the intrinsic link between the three scientific issues and the catalytic performance of H₂ generation for 2D/2D GN@ZN.

Firstly, the sunlight absorption capacity for the preparative samples has been studied by UV-vis diffuse reflectance spectra (DRS). As shown

in Fig. 8a, the BCN shows a steep photoabsorption edge at 461 nm, corresponding to an estimated band gap of 2.69 eV, indicating the marginal visible-light absorption. After thermal exfoliation treatment, the resultant g-C₃N₄ nanosheet displays slight hypsochromic shift from 461 nm to 456 nm (relevant band gap of 2.72 eV), this phenomenon is

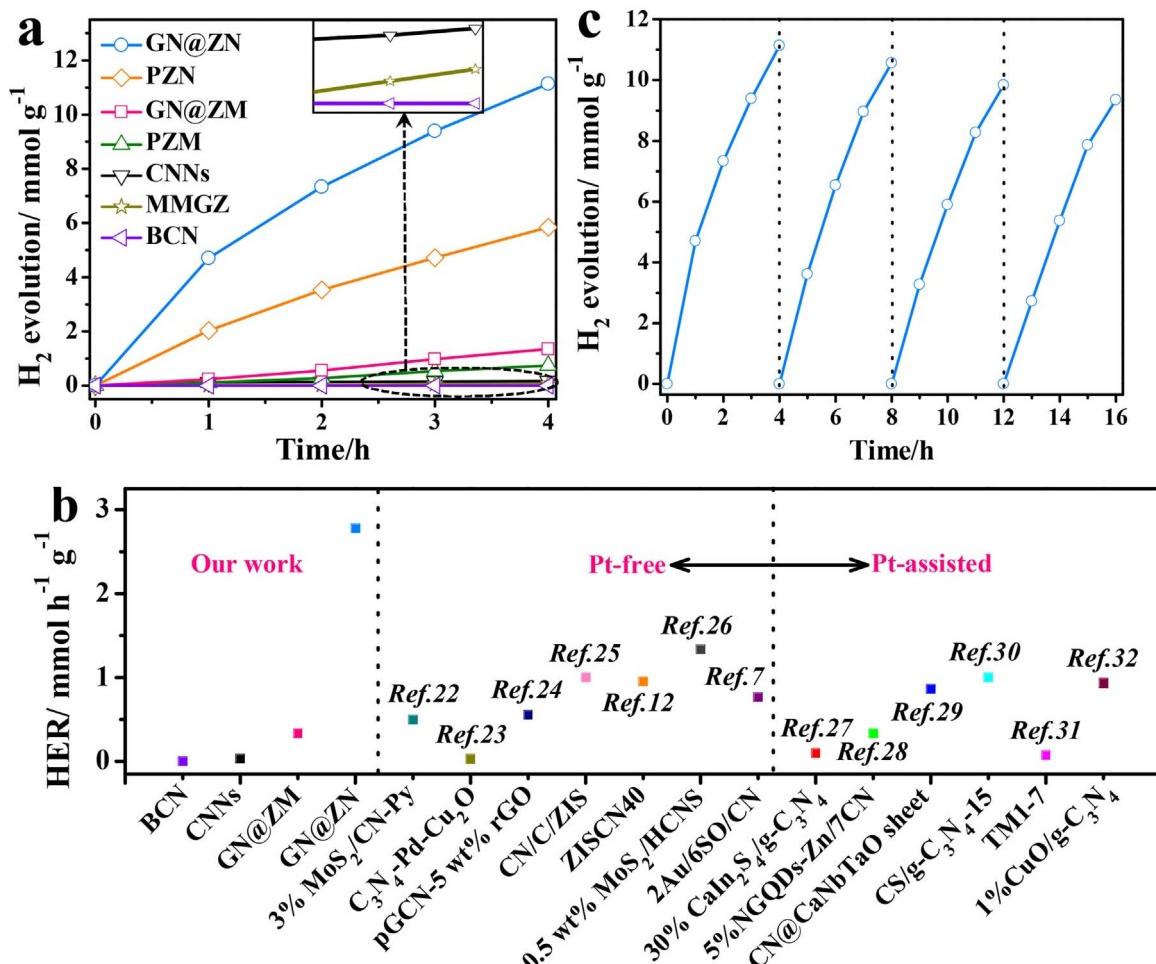


Fig. 6. (a) Time-dependent photocatalytic hydrogen evolution over different photocatalysts without the additive Pt cocatalyst under visible-light irradiation ($\lambda \geq 420$ nm). (b) Hydrogen-evolution rate (HER) over different photocatalysts in this work by contrast with the reported work related to the modification of pristine g-C₃N₄ under visible-light irradiation. (c) Cyclic stability study of photocatalytic hydrogen evolution over GN@ZN without the additive Pt cocatalyst under visible-light irradiation ($\lambda \geq 420$ nm).

due to the quantum confinement effect caused by the closely stack and interaction of g-C₃N₄ layers during the thermal treatment process [33,34]. In regard to the samples of ZnIn₂S₄ microsphere and ZnIn₂S₄ nanoleaf, the broad visible-light absorption regions at up to 620 nm and 622 nm (relevant band gaps of 2.0 eV and 1.99 eV, respectively) can be clearly found in the corresponding UV-vis DRS profiles of PZM and PZN, respectively, suggestive of a strong optical absorption ability of ZnIn₂S₄ material [12,35]. It is noted that PZN shows the much higher intensity in the range of 515–800 nm than PZM, this is because the

nano-sized leafy ZnIn₂S₄ has more contact areas with the visible light. By contrast with BCN and CNNs, obvious red shifts appear in the absorption edges of 2D/2D GN@ZN and 2D/0D GN@ZM, and their visible-light harvesting abilities are greatly enhanced, indicating that the construction of g-C₃N₄@ZnIn₂S₄ binary heterojunction composite effectively improves the sunlight absorption capacity of pure g-C₃N₄. However, the visible-light response of 2D/2D GN@ZN is much poorer than that of 2D/0D GN@ZM, which can be attributed to the photo-sensitization of ZnIn₂S₄ because only a little ZnIn₂S₄ nanosheets are

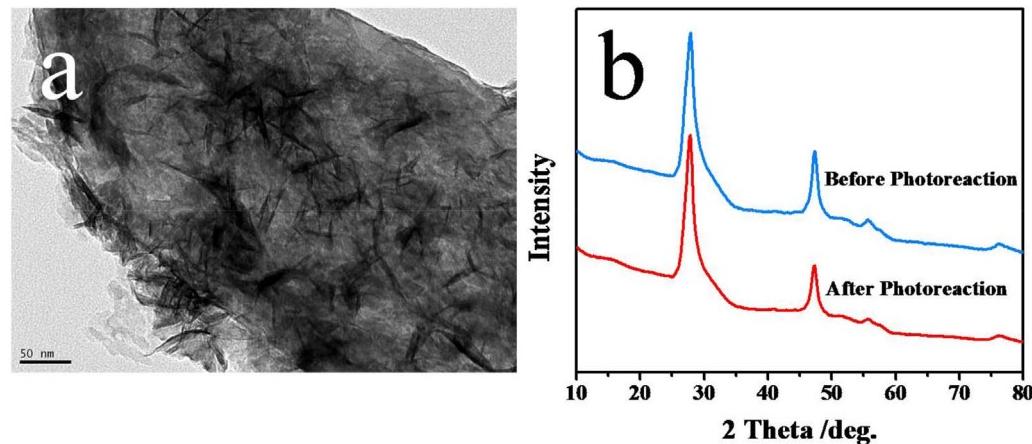


Fig. 7. TEM image (a) of GN@ZN after cyclic stability tests. X-ray diffraction patterns (b) of GN@ZN before and after four photoreactions.

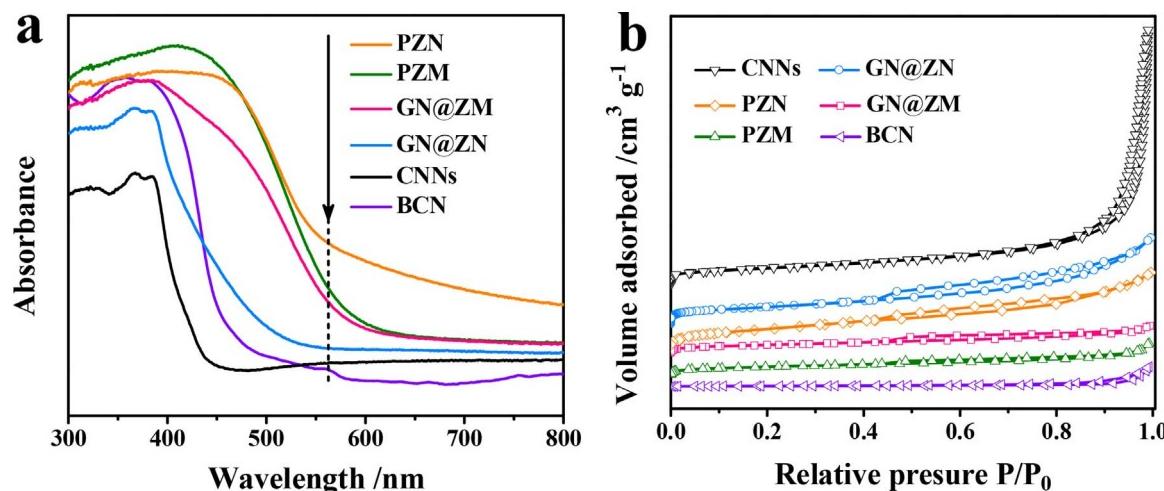


Fig. 8. UV-vis diffuse reflectance spectra (DRS) (a) and nitrogen adsorption-desorption isotherms (b) for BCN, CNNs, PZM, PZN, GN@ZM and GN@ZN.

grown on the surface of CNNs flat in 2D/2D GN@ZN composite.

Secondly, it is of great significance for exploring the changes of textural properties for obtained products. As illustrated in Fig. 8b, all photocatalysts display the typical IV N₂ adsorption-desorption isotherms with a H3-type hysteresis loop, indicative of the presence of mesopores [10,36]. The textural properties of all samples are shown in Table 1. The bulk g-C₃N₄ has low active surface area (11.31 m² g⁻¹), while the thermal exfoliated g-C₃N₄ sample exhibits significantly enlarged surface area (209.73 m² g⁻¹). Moreover, compared with the PZM sample (113.67 m² g⁻¹), the ZnIn₂S₄ nanoleaf possesses clearly enhanced active surface area of 152.27 m² g⁻¹, indicating the structure-induced textural advantages of nanoleafy structure. Accompanied by the construction of binary heterojunction system, both the two g-C₃N₄@ZnIn₂S₄ composites (117.42 m² g⁻¹ and 186.53 m² g⁻¹ for 2D/OD GN@ZM and 2D/2D GN@ZN, respectively) show the clearly reduced active surface area in comparison with CNNs, this is attributed to the covering of ZnIn₂S₄ on the surface of g-C₃N₄ nanosheet to block a large number of mesopore existed in the CNNs.

Furthermore, the photoinduced charge separation and migration efficiencies of the as-prepared photocatalysts have been investigated by photoluminescence (PL) spectra, transient photocurrent responses and electrochemical impedance spectroscopy. As displayed in Fig. 9a, an extremely intense and broad emission peak at 461 nm can be easily observed in the PL spectrum of BCN, suggestive of a fairly high photoinduced charge recombination rate due to the intrinsic geometry structure of bulk g-C₃N₄ [7]. A slight blue-shift can be found in curve of CNNs because of its widening band gap, and its fluorescence is slightly quenched, indicating a suppression of photoinduced charge recombination to a certain extent. Astonishingly, the fluorescence of two g-C₃N₄@ZnIn₂S₄ composite samples has been dramatically quenched, indicative of the advantages of binary heterojunction on the separation and migration of photoinduced charges. Notably, 2D/2D GN@ZN displays the far lower emission peak intensity than 2D/OD GN@ZM, demonstrating that the creation of 2D/2D heterojunction with high-speed

charge transfer nanochannels greatly accelerates the charge separation and transfer. By contrast with the g-C₃N₄ series samples, the two pure ZnIn₂S₄ samples show the extremely low fluorescence intensity due to the intrinsic properties of ZnIn₂S₄ material (Fig. 9b), and the PZN exhibits much lower fluorescence intensity than PZM, suggesting that the successful construction of ZnIn₂S₄ nanoleaves can effectively promote the photogenerated charge separation and migration in the photo-reaction [8,37]. These above results can be further evidenced by transient photocurrent response measurements and electrochemical impedance spectroscopy (EIS). As shown in Fig. 9c, the 2D/2D GN@ZN sample shows an extremely high photocurrent response than BCN, CNNs, PZM, PZN and 2D/OD GN@ZM, and also has the smallest radius of Nyquist circle in Fig. 9d, both suggesting that the 2D/2D GN@ZN sample possesses the dramatically decreased charge transfer resistance and excellent charge separation efficiency [38,39].

To further shed light on the effects of 2D/2D heterojunction with high-speed charge transfer nanochannels on the photoinduced charge separation and transfer efficiency, the transient fluorescence decay spectra for 2D/OD GN@ZM and 2D/2D GN@ZN have been tested. As shown in Fig. 9e, the fluorescent intensities for 2D/OD GN@ZM and 2D/2D GN@ZN display double-exponential decay kinetics. The fitting kinetic parameters (including two radiative lifetimes and their relative amplitudes) of the two g-C₃N₄@ZnIn₂S₄ composite samples are summarized in Table 2. The short lifetime (τ_1) of charge carriers increases from 2.29 ns (2D/OD GN@ZM) to 2.82 ns (2D/2D GN@ZN), and the long lifetime (τ_2) for charge carriers clearly increases from 11.97 ns (2D/OD GN@ZM) to 17.95 ns (2D/2D GN@ZN), these results manifest that massive ZnIn₂S₄ nanoleaves uniformly distribute on the surfaces of g-C₃N₄ nanosheet flat, thus generates vast contact interfaces and plentiful high-speed charge transfer nanochannels, contributing to a high-efficiency charge separation and transfer as well as a significantly prolonged radiative lifetime of charge carriers [40,41].

As a function of the above studies of three key scientific issues, it is wise to systematically reveal the main factors for remarkable photocatalytic activity. To begin with, it is interesting to compare and analyze the basis data of PZM and 2D/OD GN@ZM samples. As above mentioned, PZM and 2D/OD GN@ZM have the extremely close active surface areas (113.67 m² g⁻¹ and 117.42 m² g⁻¹ for PZM and 2D/OD GN@ZM, respectively, Table 1). And PZM and 2D/OD GN@ZM also exhibit quite close transient photocurrent response (Fig. 9c) and EIS Nyquist radius (Fig. 9d), indicative of the close photoinduced charge separation and migration efficiency. Only the visible-light absorption capacity of PZM is much stronger than that of 2D/OD GN@ZM (DRS analysis in Fig. 8a). These aforementioned data mean that if the sunlight absorption capacity plays a vital role in the photocatalytic hydrogen evolution activity, PZM would display much higher

Table 1
Textural properties for BCN, CNNs, PZM, PZN, GN@ZM and GN@ZN.

Samples	S _{BET} (m ² g ⁻¹)	Average pore size (nm)	Pore volume (cm ³ g ⁻¹)
BCN	11.31	37.52	0.10
CNNs	209.73	25.36	1.27
PZM	113.67	5.81	0.17
PZN	152.27	4.07	0.28
GN@ZM	117.42	6.27	0.17
GN@ZN	186.53	7.19	0.38

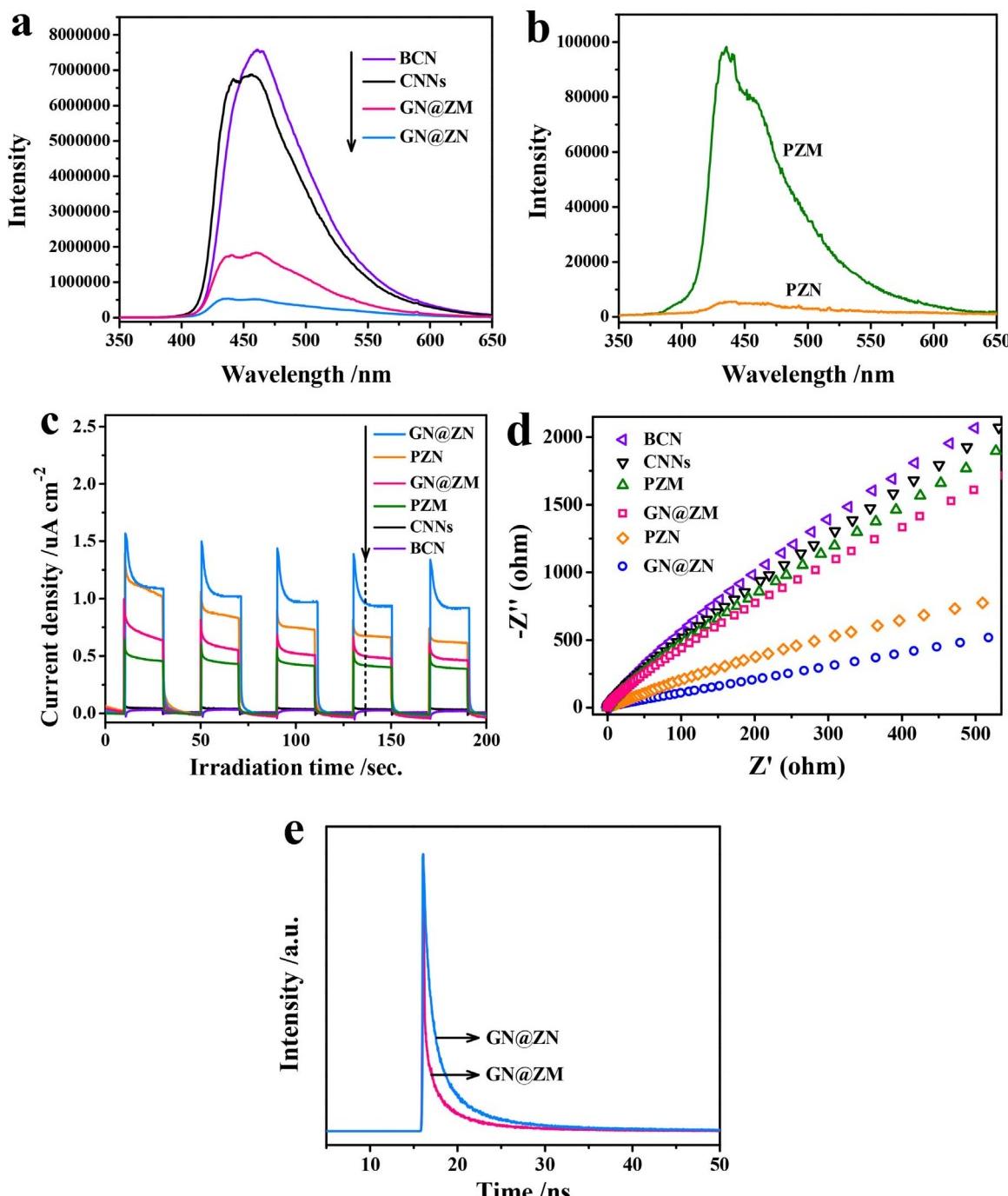


Fig. 9. (a) Photoluminescence (PL) spectra of BCN, CNNs, GN@ZM and GN@ZN. (b) Photoluminescence spectra (PL) of PZM and PZN. (c) Transient photocurrent responses and (d) EIS Nyquist plots of BCN, CNNs, PZM, PZN, GN@ZM and GN@ZN. (e) Transient fluorescence decay spectra for GN@ZM and GN@ZN.

Table 2

The fitted fluorescence lifetimes and corresponding amplitudes of photoinduced charge carriers in GN@ZM and GN@ZN.

Samples	τ_1 (ns) (Rel.%)	τ_2 (ns) (Rel.%)
GN@ZM	2.29 (42.29)	11.97 (57.71)
GN@ZN	2.82 (39.85)	17.95 (60.15)

photocatalytic activity in comparison with 2D/0D GN@ZM. However, PZM ($0.18 \text{ mmol h}^{-1} \text{ g}^{-1}$) shows a far lower photocatalytic activity relative to 2D/0D GN@ZM ($0.34 \text{ mmol h}^{-1} \text{ g}^{-1}$). All above results show that the optical absorption capacity maybe not the key factor to

promote the enhancement of photocatalytic activity of the $\text{g-C}_3\text{N}_4/\text{ZnIn}_2\text{S}_4$ composite samples.

As the above analysis, the influences of optical absorption capacity on the HER performance for CNNs and BCN could be neglected. Besides, it is clearly found that the CNNs and BCN samples have the very close PL intensity (Fig. 9a), transient photocurrent response (Fig. 9c) and EIS Nyquist radius (Fig. 9d), suggesting the close charge separation and migration efficiency. Furthermore, CNNs exhibits much larger active surface area ($209.73 \text{ m}^2 \text{ g}^{-1}$) by contrast with BCN ($11.31 \text{ m}^2 \text{ g}^{-1}$). However, CNNs does not show a greatly enhanced HER value compared with BCN as expected (Fig. 6a). These results demonstrate that the larger active surface area could hardly contribute to the higher photocatalytic H_2 evolution activity for the obtained products. This

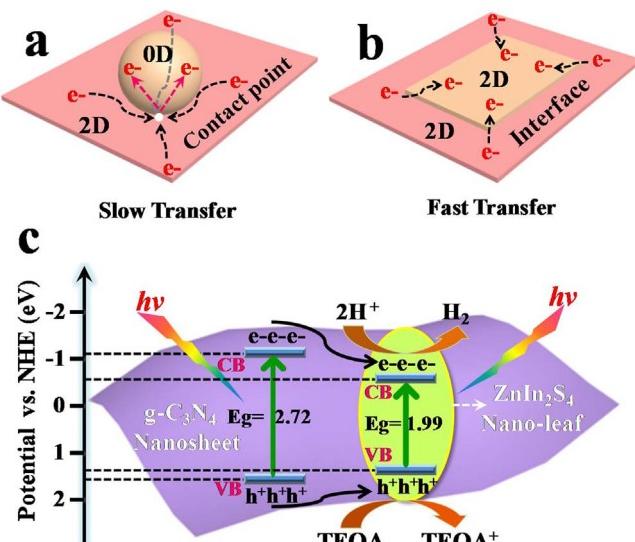


Fig. 10. Schematic illustration of contact interfaces for (a) 2D/0D heterojunction and (b) 2D/2D heterojunction. (c) Proposed mechanism of charge transfer for photocatalytic hydrogen evolution over GN@ZN under visible light irradiation ($\lambda \geq 420$ nm).

conclusion is evidenced immediately by the heterojunction construction for 2D/0D GN@ZM. The introduction of ZnIn₂S₄ microspheres on the CNNs flat significantly reduces the active surface area in comparison with original CNNs ($117.42\text{ m}^2\text{ g}^{-1}$ and $209.73\text{ m}^2\text{ g}^{-1}$ for 2D/0D GN@ZM and CNNs, respectively), however, the HER value of 2D/0D GN@ZM ($0.34\text{ mmol h}^{-1}\text{ g}^{-1}$) has indeed improved a lot than that of CNNs ($0.04\text{ mmol h}^{-1}\text{ g}^{-1}$). These above basic data comparisons reveal that the active surface area is also not the main factor for the enhanced photocatalytic HER activity of the g-C₃N₄/ZnIn₂S₄ composite samples.

Up to this point, only the last factor is left to discuss, that is whether the photoinduced charge separation and migration efficiency is the key factor for the enhancement of photocatalytic HER activity or not. This question can be solved by the analysis of HER activity between 2D/0D GN@ZM and 2D/2D GN@ZN, as well as between 2D/2D GN@ZN and MMGZ. According to the steady PL spectra (Fig. 9a), transient photocurrent response (Fig. 9c), EIS Nyquist radius (Fig. 9d) and transient fluorescence decay spectra (Fig. 9e), when micron-sized ZnIn₂S₄ microspheres have grown on the surfaces of g-C₃N₄ nanosheet flat in the face-to-point way, and only a small quantity of charge transfer nanochannels can be generated in the 2D/0D GN@ZM sample (Fig. 10a), resulting in a slow charge transport efficiency and limited photocatalytic HER activity. However, the uniformly distributed ZnIn₂S₄ nanoleaves on g-C₃N₄ nanosheet flat with face-to-face contact way can construct plentiful high-speed charge transfer nanochannels (Fig. 10b), which strongly accelerate the high-efficiency separation and migration for the photogenerated charges, ultimately contributing to a remarkable HER ($2.78\text{ mmol h}^{-1}\text{ g}^{-1}$) and a high AQY (7.05%). The importance of the above 2D/2D heterojunction with high-speed charge transfer nanochannels is also well evidenced through the comparison with a mechanically mixed g-C₃N₄ nanosheet and ZnIn₂S₄ nanoleaf sample (MMGZ). Due to a lack of high-speed charge transfer nanochannels, the photoinduced charges are severely recombined in MMGZ, leading to the negligible HER ($0.02\text{ mmol h}^{-1}\text{ g}^{-1}$). Based on the above analysis, it is confidently concluded that the outstanding photocatalytic H₂ evolution activity of 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf is mainly derived from the high photoinduced charge separation and migration efficiency by the formation of well-designed high-speed charge transfer nanochannels.

According to the aforementioned results and discussion, a proposed mechanism of charge transfer for photocatalytic hydrogen evolution has been put forward in the presence of the 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf photocatalyst under visible light irradiation

Table 3

The estimated values of band gap energy, valence band potential and conduction band potentials over g-C₃N₄ nanosheet (CNNs) and ZnIn₂S₄ nanoleaf (PZN).

Samples	Band gap energy (eV)	Valence band potential (eV)	Conduction band potential (eV)
CNNs	2.72	1.59	-1.13
PZN	1.99	1.36	-0.63

($\lambda \geq 420$ nm). As illustrated in Fig. 10c, due to the appropriate conduction band (CB) and valence band (VB) positions for g-C₃N₄ nanosheet and ZnIn₂S₄ nanoleaf (Table 3), the type-I binary heterojunction interfaces were formed, thus providing the prerequisite for the generation of the 2D/2D heterojunction with high-speed charge transfer nanochannels. When g-C₃N₄ nanosheet and ZnIn₂S₄ nanoleaf were illuminated by the visible light, both of them could be excited to produce massive photogenerated electron-hole pairs [42]. Due to the huge CB potential difference between the CB of g-C₃N₄ nanosheet and ZnIn₂S₄ nanoleaf (Table 3), the photoinduced electrons on the CB of g-C₃N₄ nanosheet could readily transfer to the CB of ZnIn₂S₄ nanoleaf via the 2D/2D heterojunction interfaces at a fast charge transport rate (Fig. 10b) [43], then reduce the hydrogen ions in aqueous solution to generate hydrogen. While the photogenerated holes on the VB of g-C₃N₄ nanosheet transferred to the VB of ZnIn₂S₄ nanoleaf, then these holes were quickly quenched by the sacrificial electron donor of TEOA. It should be emphasized that the synergistic effect of 2D g-C₃N₄ nanosheet, 2D ZnIn₂S₄ nanoleaf and 2D/2D heterojunction interfaces contributes to the formation of unique high-speed charge transfer nanochannels in the heterojunction system. These high-speed charge transfer nanochannels endowed by the 2D/2D heterojunction greatly shorten the charge migration distance and transfer time, significantly enhance the charge transport and separation efficiency, ultimately leading to a remarkable HER activity without the additive Pt cocatalyst for the 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf.

4. Conclusions

In summary, a novel 2D/2D g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf has been well designed and prepared via in-situ growing unique ZnIn₂S₄ nanoleaves on the surfaces of g-C₃N₄ nanosheets in the face-to-face way. The unusual 2D/2D heterojunction geometry significantly enlarges the contact areas relative to 2D/0D face-to-point one (g-C₃N₄ nanosheet@ZnIn₂S₄ microsphere sample). More importantly, the 2D/2D heterojunction can produce the plentiful high-speed charge transfer nanochannels in g-C₃N₄ nanosheet@ZnIn₂S₄ nanoleaf composite, which mean that the photogenerated charges could migrate along the g-C₃N₄ nanosheet to the 2D/2D heterojunction interface then to ZnIn₂S₄ nanoleaf, this process contributes to a fairly high photoinduced charge separation and migration efficiency, ultimately resulting in a remarkable visible-light-driven HER activity without the additive Pt cocatalyst, nearly 69.5, 15.4, 8.2 and 1.9 times higher than that of pure g-C₃N₄ nanosheet, pure ZnIn₂S₄ microsphere, 2D/0D g-C₃N₄ nanosheet@ZnIn₂S₄ microsphere and pure ZnIn₂S₄ nanoleaf, respectively. This work offers a new insight for the design and preparation of binary heterojunction composite with highly-efficient charge separation and transfer.

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